PCN Numb	2023	20231127004.1							PCN Date: November 27, 2023		November 27, 2023		
Title:	Add Cu as Al	ernative	native Wire Base Metal for Selected Device(s)										
Customer	Contact:	Chang	е Ма	nage	ement	team	Dept:		Qu	ality Ser	vices		
Proposed 3	L st Ship Date:		Feb	28,	2024					quests d until:	Dec	28, 2023*	
*Sample re	quests received	after De	c 28,	202	23 will	not be s	upporte	d.					
Change Ty	•												
	nbly Site				Desig	-						Material	
	nbly Process nbly Materials			\exists		<u>Sheet</u> number	change	-		Wafer B Wafer F		Process	
	anical Specifica	ion			Test		change	_		Wafer F			
	ng/Shipping/Lal					Process				Wafer F			
				Ρ	CN D	eta ils		•					
Descriptio	n of Change:												
Texas Instruments is pleased to announce the qualification of new assembly material set to add Cu as an additional bond wire option for devices listed in "Product affected" section below. Devices will remain in current assembly facility and piece part changes as follows:													
	What				Curre	nt				Additi	Additional		
Bon	d wire, Diamete	er D	,						to LF: 0.8 mil Cu to Die: 0.8 mil Cu				
Reason for	Change:												
 To align electrica Maximiz 	 Continuity of supply. 1) To align with world technology trends and use wiring with enhanced mechanical and electrical properties 2) Maximize flexibility within our Assembly/Test production sites. 3) Cu is easier to obtain and stock 												
Anticipate	d impact on F	t, Form,	Fun	ctio	n, Qua	lity or	Re lia bil	ity	(po	sitive /	nega	tive):	
None													
Impact on	Environment	al Rating	js										
	xes indicate th kes are checked												
	RoHS		REACH				Green Status			IEC 62474			
🛛 No C	hange	🛛 No C	hang	e		🛛 No	Change			🛛 No Change			
	product ider	tificatio	n res	sulti	ing fro	m this	PCN:						
None Draduat 44	for all a												
Product Af	Tected:												
ISO1042B	DW I	SO1042D) WR		I	UCC21732DW				UCC217	V R		
ISO1042B	DWR I	JCC2171	C21710DW UCC21732DWR										
ISO1042D	w lu	JCC2171	DWF	ર	l	JCC217	50DW						

Qualification Report Automotive New Product Qualification Summary (As per AEC-Q100 and JEDEC Guidelines)

Approve Date 19-October-2023

Product Attributes

Attributes	Qual Device:	Qual Device:	QBS Process Reference:	QBS Process Reference:	QBS Product Reference:
Attributes	ISO6763QDWRQ1	UCC21540QDWKRQ1	UCC23513QDWYQ1	ISO7741FQDWQ1	ISO6763QDWRQ1
Automotive Grade Level	Grade 1	Grade 1	Grade 1	Grade 1	Grade 1
Operating Temp Range (C)	-40 to 125	-40 to 125	-40 to 125	-40 to 125	-40 to 125
Product Function	Interface	Power Management	Power Management	Interface	Interface
Wafer Fab Supplier	RFAB, RFAB	MH8, MH8, MH8	RFAB, RFAB	MH8, MH8	RFAB, RFAB
Assembly Site	MLA	TAI	TAI	TAI	MLA
Package Group	SOIC	SOIC	SOIC	SOIC	SOIC
Package Designator	DW	DWK	DWY	DW	DW
Pin Count	16	14	6	16	16

QBS: Qual By Similarity

Qual Device ISO6763QDWRQ1 is qualified at MSL2 260C

Qual Device UCC21540QDWKRQ1 is qualified at MSL3 260C

Qualification Results

Data Displayed as:	Number of lots /	I otal sample siz	e / Total failed

					nopiayoa (001 01	loto / lotal	3411pic 31207	Total landa		
Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: ISO6763QDWRQ1	Qual Device: <u>UCC21540QDWKRQ1</u>	QBS Process Reference: UCC23513QDWYQ1	QBS Process Reference: ISO7741FQDWQ1	QBS Product Reference: ISO6763QDWRQ1
Test Group	A - Acce	lerated Enviror	ment St	ress Tes	its							
PC	A1	JEDEC J- STD-020 JESD22- A113	3	77	Preconditioning	MSL2 260C	-	No Fails	No Fails	-	-	No Fails
HAST	A2	JEDEC JESD22- A110	3	77	Biased HAST	130C/85%RH	96 Hours	3/231/0	3/231/0	-	-	1/77/0
AC/UHAST	A3	JEDEC JESD22- A102/JEDEC JESD22- A118	3	77	Autoclave	121C/15psig	96 Hours	3/231/0	3/231/0	-	-	1/77/0
тс	A4	JEDEC JESD22- A104 and Appendix 3	3	77	Temperature Cycle	-65C/150C	500 Cycles	3/231/0	3/231/0	-	-	1/77/0
TC-BP	A4	MIL-STD883 Method 2011	1	5	Post Temp Cycle Bond Pull	-	-	1/5/0	1/5/0	-	-	1/5/0
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	150C	1000 Hours	3/135/0	3/135/0	-	-	-
HTSL	A6	JEDEC JESD22- A103	1	45	High Temperature Storage Life	175C	500 Hours		-	-	-	1/45/0
Test Group	B - Acce	lerated Lifetime	e Simula	tion Test	s							
HTOL	B1	JEDEC JESD22- A108	3	77	Life Test	125C	1000 Hours		-	3/231/0	3/231/0	-
ELFR	B2	AEC Q100- 008	3	800	Early Life Failure Rate	125C	48 Hours	-	-	3/2400/0	3/2400/0	-
Test Group	C - Pack	age Assembly	Integrity	Tests								
WBS	C1	AEC Q100- 001	1	30	Wire Bond Shear	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0	3/90/0	3/90/0	-
WBP	C2	MIL-STD883 Method 2011	1	30	Wire Bond Pull	Minimum of 5 devices, 30 wires Cpk>1.67	Wires	3/90/0	3/90/0	3/90/0	3/90/0	-
SD	СЗ	JEDEC J- STD-002	1	15	PB Solderability	>95% Lead Coverage	-	-	-	1/15/0	-	1/15/0

Туре	#	Test Spec	Min Lot Qty	SS / Lot	Test Name	Condition	Duration	Qual Device: ISO6763QDWRQ1	Qual Device: <u>UCC21540QDWKRQ1</u>	QBS Process Reference: UCC23513QDWYQ1	QBS Process Reference: ISO7741FQDWQ1	QBS Product Reference: ISO6763QDWRQ1
SD	C3	JEDEC J- STD-002	1	15	PB-Free Solderability	>95% Lead Coverage	-	-	-	1/15/0	-	1/15/0
PD	C4	JEDEC JESD22- B100 and B108	3	10	Physical Dimensions	Cpk>1.67	-	-	-	3/30/0	-	-
Test Group	D - Die F	abrication Relia	ability Te	sts								
EM	D1	JESD61	-	-	Electromigration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
TDDB	D2	JESD35	-	-	Time Dependent Dielectric Breakdown	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
HCI	D3	JESD60 & 28	-	-	Hot Carrier Injection	-		Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
NBTI	D4	-	-	-	Negative Bias Temperature Instability	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
SM	D5	-	-	-	Stress Migration	-	-	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements	Completed Per Process Technology Requirements
Test Group	E - Elect	rical Verificatio	n Tests									
ESD	E2	AEC Q100- 002	1	3	ESD HBM	-	2000 Volts	Device specific data [1]	Device specific data [1]	-	-	1/3/0
ESD	E3	AEC Q100- 011	1	3	ESD CDM	-	1500 Volts	Device specific data [1]	Device specific data [1]	-	-	1/3/0
LU	E4	AEC Q100- 004	1	6	Latch-Up	Per AEC Q100-004	-	Device specific data [1]	Device specific data [1]	-	-	1/6/0
ED	E5	AEC Q100- 009	3	30	Electrical Distributions	Cpk>1.67 Room, hot, and cold	-	3/90/0	3/90/0	3/90/0	3/90/0	-

Preconditioning was performed for Autoclave, Unbiased HAST, THB/Biased HAST, Temperature Cycle, Thermal Shock, and HTSL, as applicable

The following are equivalent HTOL options based on an activation energy of 0.7eV : 125C/1k Hours, 140C/480 Hours, 150C/300 Hours, and 155C/240 Hours

The following are equivalent HTSL options based on an activation energy of 0.7eV : 150C/1k Hours, and 170C/420 Hours The following are equivalent Temp Cycle options per JESD47 : -55C/125C/700 Cycles and -65C/150C/500 Cycles **Ambient Operating Temperature by Automotive Grade Level:**

Grade 0 (or E): -40C to +150C

Grade 1 (or Q): -40C to +125C

Grade 2 (or T): -40C to +105C

Grade 3 (or I) : -40C to +85C

E1 (TEST): Electrical test temperatures of Qual samples (High temperature according to Grade level): Room/Hot/Cold : HTOL, ED Room/Hot : THB / HAST, TC / PTC, HTSL, ELFR, ESD & LU Room : AC/uHAST

Quality and Environmental data is available at TI's external Web site: http://www.ti.com/

For questions regarding this notice, e-mails can be sent to Change Management team or your local Field Sales Representative.

IMPORTANT NOTICE AND DISCLAIMER

TI PROVIDES TECHNICAL AND RELIABILITY DATA (INCLUDING DATASHEETS), DESIGN RESOURCES (INCLUDING REFERENCE DESIGNS), APPLICATION OR OTHER DESIGN ADVICE, WEB TOOLS, SAFETY INFORMATION, AND OTHER RESOURCES "AS IS" AND WITH ALL FAULTS, AND DISCLAIMS ALL WARRANTIES, EXPRESS AND IMPLIED, INCLUDING WITHOUT LIMITATION ANY IMPLIED WARRANTIES OF MERCHANTABILITY, FITNESS FOR A PARTICULAR PURPOSE OR NON-INFRINGEMENT OF THIRD PARTY INTELLECTUAL PROPERTY RIGHTS.

These resources are intended for skilled developers designing with TI products. You are solely responsible for (1) selecting the appropriate TI products for your application, (2) designing, validating and testing your

application, and (3) ensuring your application meets applicable standards, and any other safety, security, or other requirements. These resources are subject to change without notice. TI grants you permission to us e these resources only for development of an application that uses the TI products described in the resource. Other reproduction and display of these resources is prohibited. No license is granted to any other TI intellectual property right or to any third party intellectual property right. TI disdaims responsibility for, and you will fully indemnify TI and its representatives against, any claims, damages, costs, losses, and liabilities arising out of your use of these resources.

TI's products are provided subject to TI's Terms of Sale (<u>www.ti.com/legal/termsofsale.html</u>) or other applicable terms available either on ti.com or provided in conjunction with such TI products. TI's provision of these resources does not expand or otherwise alter TI's applicable warranties or warranty disdaimers for TI products.